Atomically Resolved Single-Walled Carbon Nanotube Intramolecular Junctions

Min Ouyang,¹ Jin-Lin Huang,¹ Chin Li Cheung,¹ Charles M. Lieber^{1,2*}

Intramolecular junctions in single-walled carbon nanotubes are potentially ideal structures for building robust, molecular-scale electronics but have only been studied theoretically at the atomic level. Scanning tunneling microscopy was used to determine the atomic structure and electronic properties of such junctions in single-walled nanotube samples. Metal-semiconductor junctions are found to exhibit an electronically sharp interface without localized junction states, whereas a more diffuse interface and low-energy states are found in metal-metal junctions. Tight-binding calculations for models based on observed atomic structures show good agreement with spectroscopy and provide insight into the topological defects forming intramolecular junctions. These studies have important implications for applications of present materials and provide a means for assessing efforts designed to tailor intramolecular junctions for nanoelectronics.

Single-walled carbon nanotubes (SWNTs) intramolecular junctions (IMJs) formed by interposing one or multiple topologic pentagonheptagon (5-7) defects (in the normal hexagonal structure) between two nanotube segments of different helicity have aroused substantial interest due to their potential for creating nanoelectronic devices (1-3). Theoretical studies of the electronic properties of model SWNT IMJs (4-9) suggest that these structures could function as molecular-size metal-semiconductor (M-S), metal-metal (M-M), or semiconductor-semiconductor building blocks with robust solid-state behavior. To date, experimental observations of bent SWNTs (10, 11) and transport through nanotube structures (11, 12) have provided only indirect evidence for the existence of IMJs. Atomically resolved scanning tunneling microscopy (STM), which has previously shown that SWNTs can exhibit a wide range of atomic structures (13-15), represents a potentially ideal technique for illuminating the properties of IMJs. The wide range of SWNT structures observed (15) underscores the importance in elucidating the atomic-level structure of suspected IMJs to define their existence (16) and to understand their electronic properties.

We report STM studies of SWNTs that resolve the atomic structures and electronic properties of M-S and M-M IMJs. The observed atomic structures of the SWNTs forming IMJs were used to construct atomic models of the junctions. Comparisons between tight-binding calculations and spatially resolved tunneling spectroscopy data were used to determine the most likely configurations of topological defects for IMJs and reveal characteristic features of the M-S and M-M IMJs. The ability to characterize IMJs at the atomic level will aid in further developing our understanding of these molecular-scale structures and will be critical to synthetic efforts aimed at "engineering" junctions.

A homemade ultrahigh vacuum STM operating at 5 K was used to characterize the structure and electronic properties of SWNTs. Sample preparation and image analysis were similar to previous studies (14, 17). Atomically resolved images of a large number (about 100) of individual SWNTs and SWNT bundles were recorded, and about 10% of these were found to exhibit stable defect features under extended scanning. Features that change with scanning are also observed and can be attributed to adsorbates (18).

A typical example of a SWNT IMJ (Fig. 1A), which is located at the center of the image, is visible at different bias voltages as a clear perturbation in the regular atomic-scale structure of the upper and lower portions of the SWNT. The fact that a 5-7 defect is not clearly visible in this region is not surprising because (i) the defect may not be located directly at the upper surface of the SWNT circumference and (ii) the local density of states, which are measured in the STM experiment, do not necessarily reflect the atom positions. This latter point has been addressed specifically in recent theoretical calculations of expected STM images for different 5-7 defect configurations (19-23). The presence of the IMJ is, however, demonstrated clearly by determining the SWNT structural indices, which

are defined by the diameter and helicity, and the electronic properties (Fig. 1B) for the upper and lower portions of the nanotube.

Analysis of Fig. 1A shows that the upper and lower portions of the nanotube have similar diameters, 1.57 ± 0.07 nm, but significantly different in its chiral angles (θ), where the angle is defined relative to the zigzag direction, for the upper and lower portions, $\theta = -3.9^{\circ} \pm 0.8^{\circ}$ and $-10.5^{\circ} \pm 0.8^{\circ}$, respectively. The very significant change in chiral angle that occurs across the local defect is strong evidence that this feature is an IMJ. Further support for this conclusion was obtained from tunneling spectroscopy data (Fig. 1B), which show clear peaks corresponding to the van Hove singularities (VHS) characteristic of the one-dimensional SWNT (13-15). The difference between the first VHS in the upper segment, 0.45 eV, is about three times smaller than the difference for the lower segment, 1.29 eV, and is thus consistent with the upper and lower portions being semiconducting and metallic, respectively (15). That is, the gap, E_{g} , between first VHS depends only on diameter (d) and not the helicity: $E_{\alpha} =$ $G\gamma_0 a_{\rm cc}/d$, where γ_0 is transfer matrix element, $a_{\rm cc}$ is the carbon-carbon bond distance, and G is 2 for semiconducting and 6 for metallic SWNTs (24). The gaps calculated using the measured diameter and our experimentally determined value of $\gamma_0 = 2.5$ eV (14, 24), 0.45 and 1.35 eV, are consistent with those measured (Fig. 1B).

We also characterized in greater detail the electronic properties of the IMJ using spatially resolved spectroscopy measurements (Fig. 1C). Examination shows that the gap defined by VHS in the semiconducting tube segment (small arrows) decays across the IMJ into the metallic segment within <1 nm, whereas the distinct spectroscopic features of the metallic tube (large arrows) appear to decay more quickly across the junction interface. The relatively sharp interface is consistent with theoretical calculations on model structures (5-8) and supports the idea that molecularscale devices could be developed from SWNT IMJs. In addition, no localized states are detected in the interface region, suggesting that the M-S junction may behave as an ideal Schottky diode. These atomic-level observations lend support to recent experiments (11, 12) that have attributed IMJs to rectifying transport data.

In comparison to previous work (10-12), our atomically resolved images enable atomic models of the junction to be constructed, analyzed theoretically, and compared with the experimental spectroscopy data. To build models of the IMJ, the SWNT (n,m) indices that correspond to a specific combination of *d* and θ (24) were determined by using an iterative projection matching method (17). The (n,m) indices define the nanotube structure through the vector $C_h = na_1 + ma_2$,

¹Department of Chemistry and Chemical Biology and ²Division of Engineering and Applied Sciences, Harvard University, Cambridge, MA 02138, USA.

^{*}To whom correspondence should be addressed. Email: cml@cmliris.harvard.edu

REPORTS

where $\mathbf{a_1}$ and $\mathbf{a_2}$ are the unit vectors of the graphene hexagonal lattice. For the semiconducting and metallic portions, these indices are (21,-2) and (22,-5), respectively. SWNT segments with these indices can be joined seamlessly along a common axis using different configurations of 5-7 defects. Two low-energy structural models are shown (Fig. 2A), which have been optimized using molecular mechanics energy minimization. Model I consists of three separated 5-7 pairs and Model II has two isolated 5-7 pairs and one 5-7/7-5 pair. It is possible to evaluate the viability of these atomic models by calculating the local electronic density of states (LDOS) and comparing these with experiment. The results from our tight-binding calculations (15, 25) (Fig. 2B) show that LDOS for Model I matches the experimental data well. Specifically, the first VHS of the semiconducting segment decays across the IMJ into the metallic segment with a decay constant similar to that in the experiment. In contrast, the LDOS calculated for Model II exhibits low-energy states around -0.10 eV, which are not observed in our experimental data. Hence, we believe that Model I can be reasonably assigned to the structure for the observed IMJ. Our new results and previous calculations (5-8) show that the absence or presence of localized states at the M-S junction reflect the specific configuration of 5-7 defects. Because this could be used to vary device properties, it will be interesting to



Fig. 1. Structure and spectroscopy of a M-S IMJ. (**A**) Atomically resolved STM image of a SWNT containing an IMJ; the junction position is highlighted with a white arrow. Black honeycomb meshes corresponding to (21,-2) and (22,-5) indices are overlaid on the upper and lower portions, respectively, of the nanotube to highlight the distinct atomic structures of these different regions. The image was recorded in the constant-current mode with electrochemically etched tungsten tips at bias voltage $V_b = 650$ mV and I = 150 pA. Bar, 1 nm. (**B**) Tunneling conductance, *dI/dV*, recorded at the upper (∇) and lower (Δ) locations indicated in (A). The data were recorded directly as the in-phase component of the current *I* by a lock-in amplifier with a 7.37-kHz modulation signal of 2-mV peak-to-peak amplitude, and the curves presented in the figures were typically averaged over six sets of raw data. The energy difference between first VHS gap in the upper semiconducting segment, 0.45 eV, and lower metallic segment, 1.29 eV, are shown. (**C**) Spatially resolved *dI/dV* acquired across the M-S IMJ at the positions indicated by the six symbols on the high-resolution image (inset) of the junction interface. The small arrows highlight the positions of the first VHS of the semiconducting (21,-2) structure and emphasize their spatial decay across the junction; the large arrows highlight the first VHS of the metallic (22,-5) structure. Bar, 1 nm.

see whether these configurations can be controlled in the future.

We also characterized a M-M IMJ junction using similar methods (Fig. 3). The atomically resolved image (Fig. 3A) suggests a large difference in diameters but similar chiral angles for the upper and lower segments of IMJ structure, $d = 1.23 \pm 0.05$ nm and $\theta = 24.3^{\circ} \pm$ 0.6° , and $d = 1.06 \pm 0.05$ nm and $\theta = 23.8^{\circ} \pm$ 0.6° , respectively. The local spectroscopy data recorded away from the IMJ region (Fig. 3B)



Fig. 2. Atomic models and electronic properties of the M-S IMJ. (A) Two different models for a (22,-5)/(21,-2) junction. Model I has three separated 5-7 pairs, and Model II has two isolated 5-7 pairs and one 5-7/7-5 pair. The filled black spheres highlight the atoms forming the 5-7 defects. The symbols in (A) are the same as in Fig. 1A, and correspond to the locations where LDOS was calculated. (B) Calculated LDOS for Model I (solid line) and Model II (dashed line). More than 2000 carbon atoms were involved for calculation for every model. The small and large black arrows highlight the same features as in Fig. 1C.

demonstrates that the magnitude of the first VHS gap for the lower segment is larger than that recorded on the upper segment. Thus, these gaps are consistent with the diameters determined from the images. Moreover, they show that both segments are metallic SWNTs. In addition, spatially resolved spectroscopy data recorded across the IMJ (Fig. 3C) shows new features not observed in the M-S IMJ discussed above; that is, there are low-energy peaks at -0.55 and -0.27 eV not present in the spectroscopy data recorded away from the junction. These peaks appear to decay slowly from the IMJ into the bulk of the larger diameter segment but quickly into the smaller segment.

We determined the (n,m) indices of the larger and smaller segments of the IMJ structure using the iterative method above and find the best fits to be for values of (11,8) and (9,6), respectively, which are both metallic tubes. To check the consistency of this assignment, tightbinding calculations (25) were used to evaluate the LDOS for isolated (11,8) and (9,6) tubes. Comparison of the calculated and experimental LDOS (Fig. 3B) shows excellent agreement and substantiates our assignment of the indices and the M-M character of the junction. The (11,8) and (9,6) SWNT segments can be joined seamlessly along a common axis using different configurations of 5-7 defects. A specific model (Fig. 4A) we analyzed consists of two separated 5-7/7-5 pairs. It is also possible to connect the (11,8) and (9,6) segments using two or three 5-7 pairs, although our calculations suggest that these are less likely (26). The LDOS obtained from our π -only tight-binding calculation (Fig. 4B) shows reasonable agreement with the experimental observation. Specifically, the lowenergy peak at -0.55 eV matches that observed in experiment; however, we do not detect the other peak at -0.27 eV in our π -only calculations. We also evaluated and compared the decay of this peak in both directions from the IMJ and found that the calculated (1.6 nm⁻¹) and experimental (1.9 nm⁻¹) decay into the (9,6) segment agree better than calculated (2.6 nm⁻¹) and experimental (4.9 nm⁻¹) decay into the (11,8) segment.

We believe that the proposed atomic model represents a reasonable description of the IMJ but also realize that our calculations have limitations. In particular, the greater structural distortions required to join the (11,8) and (9,6) tubes probably require inclusion of at least 2s and 2p orbitals to describe properly the electronic structure. More detailed calculations should help to understand the origin of all of the localized states detected experimentally as well as the interesting asymmetry in the decay of these states from the IMJ interface.

The direct atomically resolved characterization of IMJs in as-grown SWNT materials by STM has important implications and opens exciting opportunities on several fronts. We have demonstrated unambiguously that IMJs are present in SWNT samples, and statistics show that topological defects occur with a relatively high frequency in these samples grown by laser ablation, in contrast to previous expectations. The common occurrence of these defects could have important implications for the interpretation of electrical transport and mechanical measurements. These studies provide experimentally derived atomic-level junction models that

С

Fig. 3. Structure and

spectroscopy of a M-M IMJ. (A) Con-

stant-current image

of (11,8)/(9,6) junction recorded at $V_{\rm b} =$

500 mV and I = 150 pA. The white arrow highlights the junc-

tion interface. Bar, 1 nm. Symbols are as in

Fig. 1, (A) and (C).

The image of the up-

per SWNT segment is

more complex than

that found in typical

data. Although detailed analysis is be-

yond the scope of

this paper, recent cal-

structure in the im-

suggest

observed

culations

that the





age may be due to conduction electron scattering (22). (B) dI/dV, recorded at the upper (\triangle) and lower (\heartsuit) locations indicated in (A). The corresponding calculated DOS for (11,8) and (9,6) SWNTs are shown above and below the experimental curves, respectively. (C) Spatially

resolved dI/dV recorded across junction at the positions indicated in (A). New peaks at -0.55 and -0.27 eV in the junction region are highlighted by solid black and open arrows, respectively.

will enable an important dialog between experiments and further high-level calculations designed to reveal details of IMJ physics. We also believe that STM characterization of IMJs can



Fig. 4. Atomic model and electronic properties of the M-M IMJ. (A) Model of the (11,8)/(9,6) junction containing two separated 5-7/7-5 pairs, which are highlighted with solid red and blue spheres. The view presented was obtained by rotating about the axis until the observed structure was similar to the experimental image (Fig. 3A). (B) Calculated LDOS curves corresponding to the six positions indicated in (A). The solid black and open arrows correspond to the same positions highlighted in Fig. 3C. (C) Spatial decay of the localized junction state at -0.55 eV. The solid and dashed lines correspond to fits to the experimental and calculated data, respectively. The origin, negative position [(11,8) side], and positive position [(9,6) side] are indicated in (A). The decay constants k_d were obtained by fitting to exp[- k_d x].

References and Notes

- 1. S. Saito, Science 278, 77 (1997).
- 2. P. L. McEuen, Nature 393, 15 (1998).
- 3. C. Dekker, Phys. Today 52, 22 (May 1999).
- 4. B. I. Dunlap, Phys. Rev. B 49, 5643 (1994).
- Ph. Lambin, A. Fonseca, J. P. Vigneron, J. B. Nagy, A. A. Lucas, *Chem. Phys. Lett.* **245**, 85 (1995).
- 6. L. Chico, V. H. Crespi, L. X. Benedict, S. G. Louie, M. L. Cohen, *Phys. Rev. Lett.* **76**, 971 (1996).
- 7. J.-C. Charlier, T. W. Ebbesen, Ph. Lambin, *Phys. Rev. B* 53, 11108 (1996).
- 8. L. Chico, L. X. Benedict, S. G. Louie, M. L. Cohen, *Phys. Rev. B* **54**, 2600 (1996).
- R. Saito, G. Dresselhaus, M. S. Dresselhaus, *Phys. Rev.* B 53, 2044 (1996).

- J. Han, M. P. Anantram, R. L. Jaffe, J. Kong, H. Dai, *Phys. Rev. B* 57, 14983 (1998).
- Z. Yao, H. W. Ch. Postma, L. Balents, C. Dekker, *Nature* **402**, 273 (1999).
- 12. P. G. Collins, A. Zettl, H. Bando, A. Thess, R. E. Smalley, *Science* **278**, 100 (1997).
- J. W. G. Wildoer, L. C. Venema, A. G. Rinzler, R. E. Smalley, C. Dekker, *Nature* **391**, 59 (1998).
- T. W. Odom, J.-L. Huang, P. Kim, C. M. Lieber, *Nature* 391, 62 (1998).
- 15. ____, J. Phys. Chem. B 104, 2794 (2000).
- 16. For example, a recent STM study suggests that the bend in a SWNT tube is an IMJ [L. C. Venema et al., Phys. Rev. B 62, 5238 (2000)]. However, the absence of atomic resolution makes it impossible to distinguish whether the observed "kink" connects two different tubes rather than corresponding to a simple bend. In addition, the VHS peaks above and below the bend are not consistent with the SWNT diameters. Hence, it is possible that the observed spectroscopic features are due to effects of bending (15).
- 17. T. W. Odom, J.-L. Huang, P. Kim, M. Ouyang, C. M. Lieber, *J. Mater. Res.* **13**, 2380 (1998).

Evidence for Coherent Proton Tunneling in a Hydrogen Bond Network

Anthony J. Horsewill,^{1*} Nicholas H. Jones,¹ Roberto Caciuffo²

We observed coherent proton tunneling in the cyclic network of four hydrogen bonds in calix[4]arene. The tunneling frequency of 35 megahertz was revealed by a peak in the magnetic field dependence of the proton spin-lattice relaxation rate measured with field-cycling nuclear magnetic resonance in the solid state at temperatures below 80 kelvin. The amplitude of the coherent tunneling peak grows with temperature according to a Boltzmann law with energy $D/k_{\rm B} = (125 \pm 10)$ kelvin (where $k_{\rm B}$ is Boltzmann's constant). The tunneling peak can be interpreted in the context of level crossings in the region where the tunneling frequency matches the proton Larmor frequency. The tunneling spectrum reveals fine structure that we attribute to coupling between the hydrogen bonds in the network. The characteristics of the tunneling peak are interpreted in the context of the potential energy surface experienced by the hydrogen atoms in the network.

Quantum tunneling can occur when a particle with energy E encounters a potential barrier of magnitude V_0 greater than E. The tunneling probability that defines the tunneling frequency is an exponential function of the barrier properties and the particle mass, and so observations of tunneling are usually confined to particles of low mass that move over short distances.

The explicit observation of molecular tunneling has been confined to relatively few systems. For example, the rotation of symmetrical groups at low temperature and, in the life sciences, evidence for the role of hydrogen tunneling in enzyme catalysis have recently been revealed through the effects of the atomic mass on the rates of reaction by isotopic substitution (1, 2).

Here we report the direct observation of coherent tunneling associated with proton transfer among a network of four coupled hydrogen (H) bonds in which the proton motion exhibits an oscillatory motion with a well-defined frequency. The coupling between H bonds also manifests itself in fine structure. These observations not only provide an example of coherent translational tunneling but also promise to reveal insight into the fundamental mechanisms of chemical reactions.

In selecting molecules with structural properties that are liable to reveal coherent tunneling, it is important to identify structures that, in the isolated molecule at least, have degenerate tautomers that can interconvert by proton motion. To minimize coupling to the environment that would otherwise quench the oscillatory modes, the energy asymmetry of

- M. Ouyang, J.-L. Huang, C. M. Lieber, unpublished data.
- V. Meunier, P. Senet, Ph. Lambin, *Phys. Rev. B* 60, 7792 (1999).
- 20. V. Meunier, Ph. Lambin, *Phys. Rev. Lett.* **81**, 5588 (1998).
- 21. D. Orlikowski, M. B. Nardelli, J. Bernholc, C. Ronald, *Phys. Rev. Lett.* **83**, 4132 (1999).
- A. Rubio, Appl. Phys. A 68, 275 (1999).
 D. Orlikowski, M. B. Nardelli, J. Bernholc, C. Roland,
- Phys. Rev. B 61, 14194 (2000).
 24. M. S. Dresselhaus, G. Dresselhaus, P. C. Eklund, Science of Fullerenes and Carbon Nanotubes (Academic Press, San Diego, 1996).
- P. Kim, T. W. Odom, J.-L. Huang, C. M. Lieber, *Phys. Rev. Lett.* 82, 1225 (1999).
- Preliminary tight-binding calculations for these two models do not exhibit good agreement with experiment (18).
- 27. We thank M. S. Gudiksen, T. W. Odom, H. Park, and P. Kim for helpful discussion. Supported by the NSF.

11 September 2000; accepted 21 November 2000

the tautomers, which can then only arise from the interactions between molecules in the solid state, must be small. Calix-[n]arenes can meet this requirement; they are bowl-shaped macromolecules with ordered arrays of phenol-methylene oligomers (3). We studied one of the simplest members of this family, calix[4]arene (Fig. 1). The molecule has fourfold symmetry, and its shape is maintained by a cyclic network of four intramolecular H bonds at its base. There are no intermolecular H bonds. We can identify two degenerate tautomers of the isolated molecule that are related by proton transfer among the four H bonds.

Nuclear magnetic resonance (NMR) relaxometry is well established for studying molecular dynamics. Atomic motion modulates the dipole-dipole interaction between nuclei and, indirectly, drives the population changes in the nuclear spin levels that give rise to spin-lattice relaxation. As the dipolar interaction has nuclear spin operators that involve one-spin (m = 1) and two-spin flips (m = 2), the spin-lattice relaxation rate, T_1^{-1} , simultaneously samples the spectral density at the Larmor frequency, ω_L , and twice the Larmor frequency. For a nucleus with spin *I* and magnetogyric ratio γ (4, 5),

$$T_{1}^{-1}(\omega_{\rm L}) = \frac{3}{2} \gamma^{4} \hbar^{2} I(I+1) \\ \times \left[J^{(1)}(\omega_{\rm L}) + J^{(2)}(2\omega_{\rm L}) \right]$$
(1)

where \hbar is Planck's constant divided by π . The spectral density, $J^{(m)}(\omega)$, is the Fourier transform of the dipolar correlation function: $J^{(m)}(\omega)$

 $= \int_{-\infty}^{\infty} \langle F^{(m)*}(t+\tau)F^{(m)}(t)\rangle \exp(i\omega\tau)d\tau \quad (2)$

where $i = \sqrt{-1}$ and $F^{(m)}$ is the spatial part of the proton dipolar interaction, which depends

¹School of Physics and Astronomy, University of Nottingham, Nottingham, NG7 2RD, UK. ²Istituto Nazionale per la Fisica della Materia, Università di Ancona, Dipartimento di Scienze dei Materiali e della Terra, Via Brecce Bianche, I-60131 Ancona, Italy.

^{*}To whom correspondence should be addressed. Email: A.Horsewill@nottingham.ac.uk